

Data sheet acquired from Harris Semiconductor

SCHS140E

#### March 1998 - Revised October 2003

# CD54HC109, CD74HC109, CD54HCT109, CD74HCT109

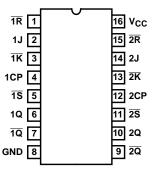
## **Dual J-K** Flip-Flop with Set and Reset **Positive-Edge Trigger**

### **Features**

- Asynchronous Set and Reset
- Schmitt Trigger Clock Inputs
- Typical  $f_{MAX} = 54MHz$  at  $V_{CC} = 5V$ ,  $C_L = 15pF$ ,  $T_{\Delta} = 25^{\circ}C$
- Fanout (Over Temperature Range)
  - Standard Outputs........... 10 LSTTL Loads - Bus Driver Outputs ...... 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity: N<sub>IL</sub> = 30%, N<sub>IH</sub> = 30% of V<sub>CC</sub> at  $V_{CC} = 5V$
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility,  $V_{IL}$ = 0.8V (Max),  $V_{IH}$  = 2V (Min)
  - CMOS Input Compatibility,  $I_I \le 1\mu A$  at  $V_{OL}$ ,  $V_{OH}$

### Pinout

CD54HC109, CD54HCT109 (CERDIP) CD74HC109, CD74HCT109 (PDIP, SOIC) TOP VIEW



### Description

The 'HC109 and 'HCT109 are dual J-K flip-flops with set and reset. The flip-flop changes state with the positive transition of Clock (1CP and 2CP).

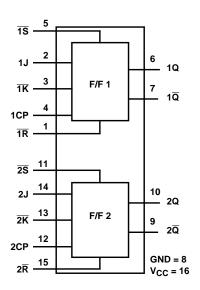
The flip-flop is set and reset by active-low  $\overline{S}$  and  $\overline{R}$ , respectively. A low on both the set and reset inputs simultaneously will force both Q and  $\overline{Q}$  outputs high. However, both set and reset going high simultaneously results in an unpredictable output condition.

### Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE		
CD54HC109F3A	-55 to 125	16 Ld CERDIP		
CD54HCT109F3A	-55 to 125	16 Ld CERDIP		
CD74HC109E	-55 to 125	16 Ld PDIP		
CD74HC109M	-55 to 125	16 Ld SOIC		
CD74HC109MT	-55 to 125	16 Ld SOIC		
CD74HC109M96	-55 to 125	16 Ld SOIC		
CD74HCT109E	-55 to 125	16 Ld PDIP		
CD74HCT109M	-55 to 125	16 Ld SOIC		
CD74HCT109MT	-55 to 125	16 Ld SOIC		
CD74HCT109M96	-55 to 125	16 Ld SOIC		

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

## Functional Diagram



**TRUTH TABLE** 

		INPUTS			OUTPUTS			
S	R	СР	J	K	Q	Q		
L	Н	Х	Х	Х	Н	L		
Н	L	Х	Х	Х	L	Н		
L	L	Х	Х	Х	H (Note 1)	H (Note 1)		
Н	Н	1	L	L	L	Н		
Н	Н	1	Н	L	Tog	ggle		
Н	Н	1	L	Н	No C	hange		
Н	Н	1	Н	Н	Н	L		
Н	Н	L	Х	Х	No Change			

H= High Level (Steady State)

L= Low Level (Steady State)

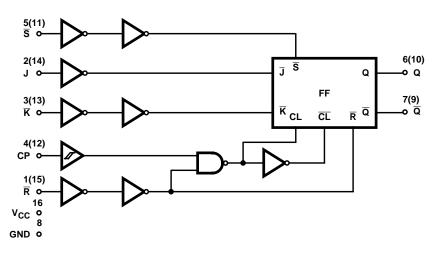
X= Don't Care

↑= Low-to-High Transition

NOTE:

1. Unpredictable and unstable condition if both  $\overline{S}$  and  $\overline{R}$  go high simultaneously

## Logic Diagram



### **Absolute Maximum Ratings**

DC Supply Voltage, V <sub>CC</sub> 0.5V to 7V
DC Input Diode Current, I <sub>IK</sub>
For $V_1 < -0.5V$ or $V_1 > V_{CC} + 0.5V$ ±20mA
DC Drain Current, per Output, IO
For -0.5V < V <sub>O</sub> < V <sub>CC</sub> + 0.5V
DC Output Diode Current, I <sub>OK</sub>
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ ±20mA
DC Output Source or Sink Current per Output Pin, IO
For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$ ±25mA
DC V <sub>CC</sub> or Ground Current, I <sub>CC</sub>

### **Thermal Information**

Thermal Resistance (Typical, Note 2) $\theta_{JA}$ ( ${}^{\circ}$ C/W	/)
E (PDIP) Package 67	
M (SOIC) Package	
Maximum Junction Temperature (Hermetic Package or Die) 175	5°C
Maximum Junction Temperature (Plastic Package) 150	
Maximum Storage Temperature Range65°C to 150	$0^{\circ}$ C
Maximum Lead Temperature (Soldering 10s)30	OoC
(SOIC - Lead Tips Only)	

### **Operating Conditions**

Temperature Range, T <sub>A</sub> 55°C to 125°C
Supply Voltage Range, V <sub>CC</sub>
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub>
C <sub>P</sub> Input Rise and Fall Time, t <sub>r</sub> , t <sub>f</sub>
2V 1.0ms (Max)
4.5V 1.0ms (Max)
6V 1.0ms (Max)
Input Rise and Fall Time (All Inputs Except C <sub>P</sub> ), t <sub>r</sub> , t <sub>f</sub>
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

2. The package thermal impedance is calculated in accordance with JESD 51-7

### **DC Electrical Specifications**

		TEST CONDITIONS			25°C			-40°C TO 85°C		-55°C TO 125°C			
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
HC TYPES													
High Level Input	V <sub>IH</sub>	=	-	2	1.5	-	-	1.5	-	1.5	-	V	
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	٧	
				6	4.2	-	-	4.2	-	4.2	-	٧	
Low Level Input	V <sub>IL</sub>	-	-	2	-	-	0.5	-	0.5	-	0.5	٧	
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	٧	
				6	-	-	1.8	-	1.8	-	1.8	V	
High Level Output	V <sub>OH</sub>	V <sub>IH</sub> or	-0.02	2	1.9	-	-	1.9	-	1.9	-	٧	
Voltage CMOS Loads		$V_{IL}$		4.5	4.4	-	-	4.4	-	4.4	-	٧	
				6	5.9	-	-	5.9	-	5.9	-	٧	
High Level Output			-	-	-	-	-	-	-	-	-	٧	
Voltage TTL Loads			-4	4.5	3.96	-	-	3.84	-	3.7	-	V	
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V	

### DC Electrical Specifications (Continued)

			ST ITIONS			25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Low Level Output	V <sub>OL</sub>	V <sub>IH</sub> or	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads		V <sub>IL</sub>		4.5	-	-	0.1	-	0.1	-	0.1	V
				6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output			-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	-	4	-	40	-	80	μА
HCT TYPES												
High Level Input Voltage	V <sub>IH</sub>	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	II	V <sub>CC</sub> and GND	-	5.5	-		±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	5.5	-	-	4	-	40	-	80	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI <sub>CC</sub> (Note 3)	V <sub>CC</sub> - 2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА

### NOTE:

### **HCT Input Loading Table**

INPUT	UNIT LOADS
All	0.3

NOTE: Unit Load is  $\Delta I_{CC}$  limit specified in DC Electrical Specifications table, e.g.,  $360\mu A$  max at  $25^{\circ}C$ .

<sup>3.</sup> For dual-supply systems theoretical worst case ( $V_I$  = 2.4V,  $V_{CC}$  = 5.5V) specification is 1.8mA.

## **Prerequisite For Switching Specifications**

		TEST	v <sub>cc</sub>		25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	•			•							
Setup Time J, K, to CP	tsu	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
Hold Time J, K, to CP	t <sub>H</sub>	-	2	5	-	-	5	-	5	-	ns
			4.5	5	-	-	5	-	5	-	ns
			6	5	-	-	5	-	5	-	ns
Removal Time $\overline{R}$ , $\overline{S}$ , to CP	t <sub>REM</sub>	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
Pulse Width CP, R, S	t <sub>W</sub>	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
CP Frequency	f <sub>MAX</sub>	-	2	6	-	-	5	-	4	-	MHz
			4.5	30	-	-	25	-	20	-	MHz
			6	35	-	-	29	-	23	-	MHz
HCT TYPES	-	•								•	
Setup Time J, K to CP	tsu	-	4.5	18	-	-	23	-	27	-	ns
Hold Time J, $\overline{K}$ to CP	t <sub>H</sub>	-	4.5	3	-	-	3	-	3	-	ns
Removal Time $\overline{R}$ , $\overline{S}$ , to CP	t <sub>REM</sub>	-	4.5	18	-	-	23	-	27	-	ns
Pulse Width CP, R, S	t <sub>W</sub>	-	4.5	18	-	-	23	-	27	-	ns
CP Frequency	f <sub>MAX</sub>	-	4.5	27	-	-	22	-	18	-	MHz

## Switching Specifications Input $t_{\text{r}},\,t_{\text{f}}=6\text{ns}$

		TEST	v <sub>cc</sub>		25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES											
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	-	175	1	220	-	265	ns
$CP \rightarrow Q, \overline{Q}$		C <sub>L</sub> = 50pF	4.5	-	-	35	-	44	-	53	ns
		C <sub>L</sub> = 15pF	5	-	14	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	30	-	37	-	45	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	-	120	-	150	-	180	ns
$\overline{S} \to Q$		C <sub>L</sub> = 50pF	4.5	-	-	24	-	30	-	36	ns
		C <sub>L</sub> = 15pF	5	-	9	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	20	-	26	-	31	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	-	155	-	195	-	235	ns
$\overline{S} \to \overline{Q}$		C <sub>L</sub> = 50pF	4.5	-	-	31	-	39	-	47	ns
		C <sub>L</sub> = 15pF	5	-	13	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	26	-	33	-	40	ns

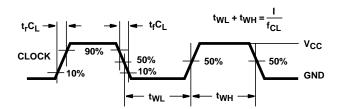
## Switching Specifications Input $t_{f},\,t_{f}=6\text{ns}$ (Continued)

		TEST	v <sub>cc</sub>		25°C		-40°C 1	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	-	185	-	230	-	280	ns
$\overline{R}  o Q$		C <sub>L</sub> = 50pF	4.5	-	-	37	-	46	-	56	ns
		C <sub>L</sub> = 15pF	5	-	15	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	31	-	39	-	48	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	-	170	-	215	-	255	ns
$\overline{\mathbb{R}} \to \overline{\mathbb{Q}}$		C <sub>L</sub> = 50pF	4.5	-	-	34	-	43	-	51	ns
		C <sub>L</sub> = 15pF	5	-	14	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	29	-	37	-	43	ns
Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2	-	-	75	-	95	-	110	ns
		C <sub>L</sub> = 50pF	4.5	-	-	15	-	19	-	22	ns
		C <sub>L</sub> = 50pF	6	-	-	13	-	16	-	19	ns
Input Capacitance	C <sub>I</sub>	-	-	-	-	10	-	10	-	10	pF
CP Frequency	f <sub>MAX</sub>	C <sub>L</sub> = 15pF	5	-	60	-	-	-	-	-	MHz
Power Dissipation Capacitance (Notes 4, 5)	C <sub>PD</sub>	-	5	-	30	-	-	-	-	-	pF
HCT TYPES						•		•	•		
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	40	-	50	-	60	ns
$CP \rightarrow Q, \overline{Q}$		C <sub>L</sub> = 15pF	5	-	17	-	-	-	-	-	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	30	-	38	-	45	ns
$\overline{S} \to Q$		C <sub>L</sub> = 15pF	5	-	12	-	-	-	-	-	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	45	-	56	-	68	ns
$\overline{S}  o \overline{Q}$		C <sub>L</sub> = 15pF	5	-	19	-	-	-	-	-	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	45	-	56	-	68	ns
$\overline{R} \to Q$		C <sub>L</sub> = 15pF	5	-	19	-	-	-	-	-	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	37	-	46	-	56	ns
$\overline{R}  o \overline{Q}$		C <sub>L</sub> = 15pF	5	-	15	-	-	-	-	-	ns
Transition Time (Figure 5)	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	C <sub>I</sub>	-	-	-	-	10	-	10	-	10	pF
CP Frequency	f <sub>MAX</sub>	CL = 15pF	5	-	54	-	-	-	-	-	MHz
Power Dissipation Capacitance (Notes 4, 5)	C <sub>PD</sub>	-	5	-	33	-	-	-	-	-	pF

<sup>4.</sup>  $C_{\mbox{\scriptsize PD}}$  is used to determine the dynamic power consumption, per flip-flop.

<sup>5.</sup>  $P_D = C_{PD} \ V_{CC}^2 \ f_i + \Sigma \ C_L \ f_o$  where  $f_i$  = input frequency,  $f_o$  = output frequency,  $C_L$  = output load capacitance,  $V_{CC}$  = supply voltage.

### Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V $_{CC}$  to 90% V $_{CC}$  in accordance with device truth table. For f $_{MAX}$ , input duty cycle = 50%.

FIGURE 7. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

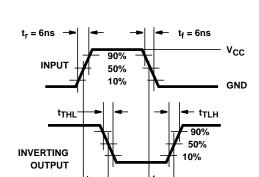


FIGURE 9. HC AND HCU TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC

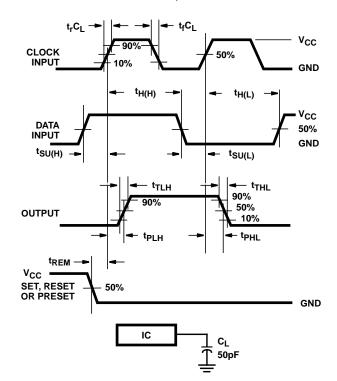
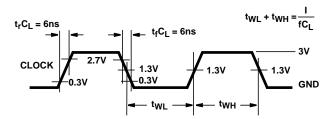


FIGURE 11. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS



NOTE: Outputs should be switching from 10% V $_{CC}$  to 90% V $_{CC}$  in accordance with device truth table. For f $_{MAX}$ , input duty cycle = 50%.

FIGURE 8. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

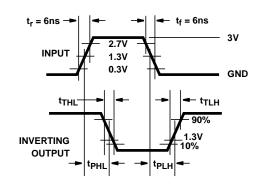


FIGURE 10. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

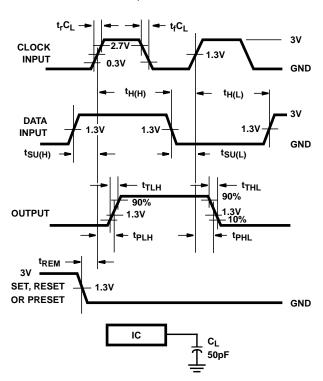


FIGURE 12. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

5-Sep-2011

### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login
5962-9070101MEA	ACTIVE	CDIP	J	16	1	TBD	Call TI	Call TI	
CD54HC109F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	
CD54HCT109F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	
CD74HC109E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HC109EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HC109M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC109M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC109M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC109M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC109ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC109MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC109MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC109MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HC109MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT109E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HCT109EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
CD74HCT109M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT109M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT109M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT109M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	





www.ti.com 5-Sep-2011

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
CD74HCT109ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT109MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT109MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT109MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
CD74HCT109MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF CD54HC109, CD54HCT109, CD74HC109, CD74HCT109:





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● Catalog: CD74HC109, CD74HCT109

• Military: CD54HC109, CD54HCT109

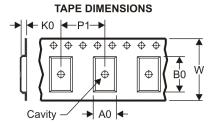
NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications



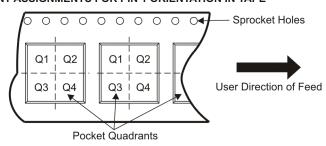
### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

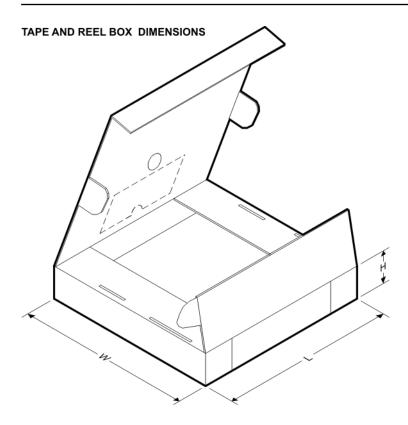
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC109M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT109M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1





\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC109M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HCT109M96	SOIC	D	16	2500	333.2	345.9	28.6

### 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

## N (R-PDIP-T\*\*)

### PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



## D (R-PDS0-G16)

### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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